

EAST - [temp.wsp:1]

File View Edit Tools Window Help

Drafts
 ISNR:
 ISNR:
 Pending
 Active
 L1: (2) ("6088276").PN.
 L2: (1) "5274598".PN.
 L3: (1) "5353255".PN.
 L4: (1) "5495440".PN.
 L5: (1) "5610871".PN.
 L6: (1) "5850367".PN.
 L8: (39685) sense adj (amplifier or amplifiers)
 L9: (320) main adj2 8
 L10: (3573) writ64 adj (driver or drivers)
 L11: (30) 9 and 10
 L12: (2156851) higher
 L13: (1356) 8 near8 12
 L14: (91) 10 and 13
 L15: (43322) sram
 L16: (205) 15 same 10
 L17: (12) 15 same 9
 L17: (12) 15 and (9 or 13)
 Failed
 Saved
 Favorites
 Tagged (0)
 UDC
 Queue
 Trash

DBs: USPAT, US-PGPUB, EPO, JPC, Plurals
 Default operator: OR Highlight all hit terms initially

16 and (9 or 13)

Fig 7
 365/205
 194, 189.05
 T 2

365 form 365 form 365 form 365 form 365 form

	u	l	Document ID	Issue Dat	Pages	Title	Current OR	Current XR	Retrieval	Inventor
1	<input type="checkbox"/>	<input type="checkbox"/>	US 20040130	20040708	30	Semiconductor memory de	365/145			Nakase, Yasunobu
2	<input type="checkbox"/>	<input type="checkbox"/>	US 5886919	19990323	22	Multi-port semiconducto	365/69	257/E27.09		Morikawa, Kouji
3	<input type="checkbox"/>	<input type="checkbox"/>	US 5773892	19980630	22	Multi-port semiconducto	257/758	257/775		Morikawa, Kouji
4	<input type="checkbox"/>	<input type="checkbox"/>	US 5724292	19980303	49	Static Semiconductor me	365/207	365/154		Wada, Tomohisa
5	<input type="checkbox"/>	<input type="checkbox"/>	US 5659515	19970819	40	Semiconductor memory de	365/222	365/230.03		Matsuo, Ryuichi
6	<input type="checkbox"/>	<input type="checkbox"/>	US 5659513	19970819	91	Static semiconductor me	365/205	327/51		Hirose, Toshihiro
7	<input type="checkbox"/>	<input type="checkbox"/>	US 5629900	19970513	91	Semiconductor memory de	365/230.03	365/189.01		Hirose, Toshihiro
8	<input type="checkbox"/>	<input type="checkbox"/>	US 5544105	19960806	91	Static semiconductor me	365/189.11	365/189.01		Hirose, Toshihiro

Desktop

Inbox - Mail - eDAN Ve - EAST - [L - Applicatio - PALM Re - RealPlay -

- Drafts
- ISNR:
- Pending
- Active
 - L2: (0) "10677012"
 - L3: (1) "10/677012"
 - L1: (1749) (365/205).CCLS.
- Failed
- Saved
- Favorites
- Tagged (0)
- UDC
- Queue
- Trash

Search
Lib
Browse
Queue

DBs USPAT: US-PGPUB: EPO: JPO: DERV

☒ Highlight all hit terms initially

365/205

BFS1
 ISNR
 Image
 Text
 HTML

	U	1	Document ID	Issue Dat	Pages	Title	Current OR	Curra
14	<input type="checkbox"/>	<input type="checkbox"/>	US 20040100	20040527	21	Semiconductor memory de	365/205	
15	<input type="checkbox"/>	<input type="checkbox"/>	US 20040100	20040527	16	Semiconductor memory de	365/205	
16	<input type="checkbox"/>	<input type="checkbox"/>	US 20040095	20040520	36	Semiconductor memory de	365/205	365/2
17	<input type="checkbox"/>	<input type="checkbox"/>	US 20040095	20040520	11	Sensing circuit	365/205	